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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





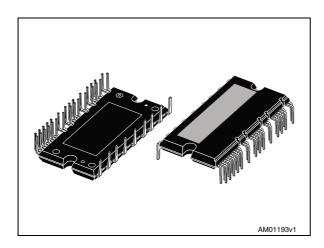




STGIPL30C60-H

SLLIMM™ (small low-loss intelligent molded module) IPM, 3-phase inverter, 30 A, 600 V short-circuit rugged IGBT

Datasheet - preliminary data



Features

- IPM 30 A, 600 V 3-phase IGBT inverter bridge including control ICs for gate driving and freewheeling diodes
- · Short-circuit rugged IGBTs
- V_{CE(sat)} negative temperature coefficient
- 3.3 V, 5 V, 15 V CMOS/TTL inputs comparators with hysteresis and pull down/pull up resistors
- · Undervoltage lockout
- Internal bootstrap diode
- Interlocking function
- Smart shut down function
- Comparators for fault protection against overtemperature and overcurrent
- Op amps for advanced current sensing
- DBC substrate leading to low thermal resistance
- Isolation rating of 2500 V_{rms}/min

• 5 kΩ NTC for temperature control

UL Recognized: UL1557 file E81734

Applications

- 3-phase inverters for motor drives
- Home appliances, such as washing machines, refrigerators, air conditioners and sewing machines

Description

This intelligent power module provides a compact, high performance AC motor drive in a simple, rugged design. Combining ST proprietary control ICs with the most advanced short-circuitrugged IGBT system technology, this device is ideal for 3-phase inverters in applications such as home appliances and air conditioners. SLLIMM™ is a trademark of STMicroelectronics.

Table 1. Device summary

Order code	Marking	Package	Packaging
STGIPL30C60-H	GIPL30C60-H	SDIP-38L	Tube

July 2013 DocID024585 Rev 4 1/24

Contents STGIPL30C60-H

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1 Internal block diagram and pin configuration

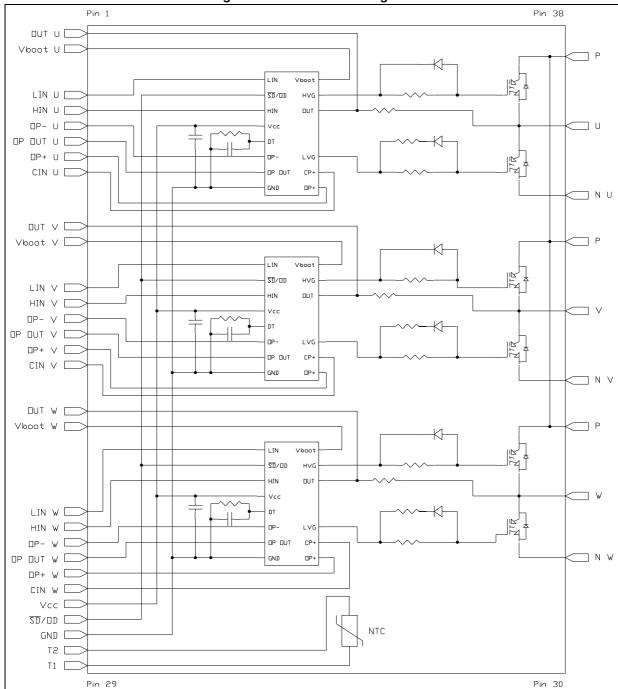


Figure 1. Internal block diagram

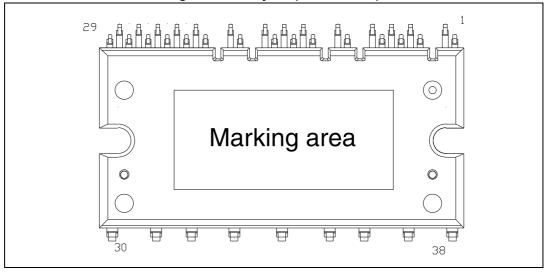
Table 2. Pin description

Pin	Symbol	Description
1	OUT _U	High side reference output for U phase
2	V _{boot U}	Bootstrap voltage for U phase
3	LIN _U	Low side logic input for U phase
4	HIN _U	High side logic input for U phase
5	OP- _U	Op amp inverting input for U phase
6	OP _{OUT U}	Op amp output for U phase
7	OP+ _U	Op amp non inverting input for U phase
8	CIN _U	Comparator input for U phase
9	OUT _V	High side reference output for V phase
10	V _{boot V}	Bootstrap voltage for V phase
11	LIN _V	Low side logic input for V phase
12	HIN _V	High side logic input for V phase
13	OP- _V	Op amp inverting input for V phase
14	OP _{OUT V}	Op amp output for V phase
15	OP+ _V	Op amp non inverting input for V phase
16	CIN _V	Comparator input for V phase
17	OUT _W	High side reference output for W phase
18	V _{boot W}	Bootstrap voltage for W phase
19	LIN _W	Low side logic input for W phase
20	HIN _W	High side logic input for W phase
21	OP-W	Op amp inverting input for W phase
22	OP _{OUT W}	Op amp output for W phase
23	OP+ _W	Op amp non inverting input for W phase
24	CIN _W	Comparator input for W phase
25	V _{CC}	Low voltage power supply
26	SD / OD	Shut down logic input (active low) / open drain (comparator output)
27	GND	Ground
28	T ₂	NTC thermistor terminal 2
29	T ₁	NTC thermistor terminal 1
30	N _W	Negative DC input for W phase
31	W	W phase output
32	Р	Positive DC input
33	N _V	Negative DC input for V phase
34	V	V phase output

Table 2. Pin description (continued)

Pin	Symbol	Description
35	Р	Positive DC input
36	N _U	Negative DC input for U phase
37	U	U phase output
38	Р	Positive DC input

Figure 2. Pin layout (bottom view)



Electrical ratings STGIPL30C60-H

2 Electrical ratings

2.1 Absolute maximum ratings

Table 3. Inverter part

Symbol	Parameter	Value	Unit
V _{PN}	Supply voltage applied between P-N $_{\rm U}$, N $_{\rm V}$, N $_{\rm W}$	450	V
V _{PN(surge)}	Supply voltage (surge) applied between P-N $_{\rm U}$, N $_{\rm V}$, N $_{\rm W}$	500	V
V _{CES}	Each IGBT collector emitter voltage (V _{IN} ⁽¹⁾ = 0)	600	V
± I _C	Each IGBT continuous collector current at T _C = 25°C	30	Α
± I _{CP} ⁽²⁾	Each IGBT pulsed collector current	60	Α
P _{TOT}	Each IGBT total dissipation at T _C = 25°C	56	W
t _{scw}	Short circuit withstand time, $V_{CE} = 0.5 V_{(BR)CES}$ $T_j = 125 ^{\circ}\text{C}, V_{CC} = V_{boot} = 15 \text{ V}, V_{IN} ^{(1)} = 0 \div 5 \text{ V}$	5	μs

^{1.} Applied between HIN_i , LIN_i and GND for i = U, V, W

Table 4. Control part

Symbol	Parameter	Min.	Max.	Unit
V _{OUT}	Output voltage applied between OUT _U , OUT _V , OUT _W - GND	V _{boot} - 21	V _{boot} + 0.3	V
V _{CC}	Low voltage power supply	- 0.3	21	V
V _{CIN}	Comparator input voltage	- 0.3	V _{CC} + 0.3	V
V _{op+}	OPAMP non-inverting input	- 0.3	V _{CC} + 0.3	V
V _{op} -	OPAMP inverting input	- 0.3	V _{CC} + 0.3	V
V _{boot}	Bootstrap voltage	- 0.3	620	V
V _{IN}	Logic input voltage applied between HIN, LIN and GND	- 0.3	15	V
V _{SD/OD}	Open drain voltage	- 0.3	15	V
dV _{OUT} /dt	Allowed output slew rate		50	V/ns

^{2.} Pulse width limited by max junction temperature

STGIPL30C60-H Electrical ratings

Table 5. Total system

Symbol	Parameter	Value	Unit
V _{ISO}	Isolation withstand voltage applied between each pin and heatsink plate (AC voltage, t = 60sec.)	2500	V
T _j	Power chips operating junction temperature	-40 to 150	°C
T _C	Module case operation temperature	-40 to 125	°C

2.2 Thermal data

Table 6. Thermal data

Symbol	Parameter	Value	Unit
R ., , ,	Thermal resistance junction-case single IGBT	2.2	°C/W
$R_{th(j-c)}$	Thermal resistance junction-case single diode	5	°C/W

3 Electrical characteristics

 $T_i = 25$ °C unless otherwise specified.

Table 7. Inverter part

Cumbal	Parameter	Test condition	Value			Unit
Symbol	i didiliotoi	rest condition	Min.	Тур.	Max.	J OIIII
V	Collector-emitter	$V_{CC} = V_{Boot} = 15 \text{ V}, V_{IN}^{(1)} = 0 \div 5 \text{ V},$ $I_{C} = 30 \text{ A}$	-	1.9		V
V _{CE(sat)}	saturation voltage	$V_{CC} = V_{Boot} = 15 \text{ V}, V_{IN}^{(1)} = 0 \div 5 \text{ V},$ $I_{C} = 30 \text{ A}, T_{J} = 125 ^{\circ}\text{C}$	-	2.2		7 V
I _{CES}	Collector-cut off current (V _{IN} ⁽¹⁾ =0 "logic state")	V _{CE} = 550 V V _{CC} = V _{boot} = 15 V	-		150	μΑ
V _F	Diode forward voltage	$V_{IN}^{(1)} = 0$ "logic state", $I_C = 30 \text{ A}$	-	2.0	2.3	V
Inductive	load switching time and	energy				
t _{on}	Turn-on time		-	440		
t _{c(on)}	Crossover time (on)	N 999 V	-	190		
t _{off}	Turn-off time	$V_{DD} = 300 \text{ V},$ $V_{CC} = V_{boot} = 15 \text{ V},$	-	780		ns
t _{c(off)}	Crossover time (off)	$V_{IN}^{(1)} = 0 \div 5 V,$	-	135		
t _{rr}	Reverse recovery time	I _C = 30 A (see <i>Figure 3</i>)	-	100		1
E _{on}	Turn-on switching losses	(-	870		<i>u</i> 1
E _{off}	Turn-off switching losses		-	740		- μJ

^{1.} Applied between HIN; LIN; and GND for i = U, V, W.

Note: t_{on} and t_{off} include the propagation delay time of the internal drive. $t_{C(ON)}$ and $t_{C(OFF)}$ are the switching time of IGBT itself under the internally given gate driving condition.

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Figure 3. Switching time test circuit



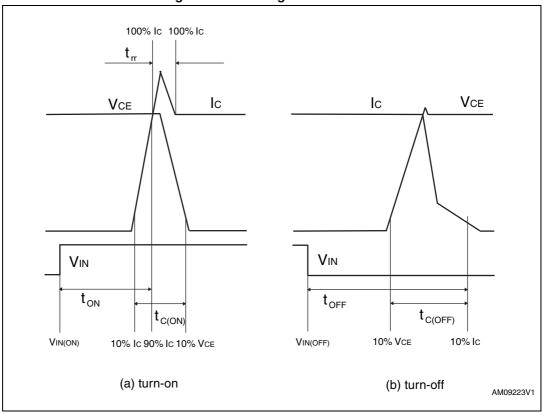


Figure 4 "Switching time definition" refers to HIN, LIN inputs (active high).

3.1 Control part

Table 8. Low voltage power supply ($V_{CC} = 15 \text{ V}$ unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{cc_hys}	V _{cc} UV hysteresis		1.2	1.5	1.8	V
V _{cc_thON}	V _{cc} UV turn ON threshold		11.5	12	12.5	V
V _{cc_thOFF}	V _{cc} UV turn OFF threshold		10	10.5	11	V
I _{qccu}	Undervoltage quiescent supply current	V _{CC} = 10 V SD /OD = 5 V; LIN = 0 HIN = 0, CIN = 0			450	μΑ
I _{qcc}	Quiescent current	V _{CC} = 15 V SD /OD = 5 V; LIN = 0 HIN = 0, CIN = 0			3.5	mA
V _{ref}	Internal comparator (CIN) reference voltage		0.5	0.54	0.58	V

Table 9. Bootstrapped voltage ($V_{CC} = 15 \text{ V}$ unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
$V_{\rm BS_hys}$	V _{BS} UV hysteresis		1.2	1.5	1.8	٧
V _{BS_thON}	V _{BS} UV turn ON threshold		11.1	11.5	12.1	٧
V _{BS_thOFF}	V _{BS} UV turn OFF threshold		9.8	10	10.6	٧
I _{QBSU}	Undervoltage V _{BS} quiescent current	V_{BS} < 9 V SD/OD = 5 V; LIN = 0 and HIN = 5 V; CIN = 0		70	110	μΑ
I _{QBS}	V _{BS} quiescent current	$V_{BS} = 15 \text{ V}$ SD/OD = 5 V; LIN = 0 and HIN = 5 V; CIN = 0		200	300	μΑ
R _{DS(on)}	Bootstrap driver on resistance	LVG ON		120		Ω

Table 10. Logic inputs (V_{CC} = 15 V unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{il}	Low logic level voltage		0.8		1.1	V
V _{ih}	High logic level voltage		1.9		2.25	V
I _{HINh}	HIN logic "1" input bias current	HIN = 15 V	20	40	100	μΑ
I _{HINI}	HIN logic "0" input bias current	HIN = 0 V			1	μΑ
I _{LINh}	LIN logic "1" input bias current	LIN = 15 V	20	40	100	μΑ
I _{LINI}	LIN logic "0" input bias current	LIN = 0 V			1	μΑ
I _{SDh}	SD logic "0" input bias current	SD = 15 V	30	120	300	μΑ
I _{SDI}	SD logic "1" input bias current	SD = 0 V			3	μΑ
Dt	Dead time	see Figure 7		1.2		μs

Table 11. OPAMP characteristics (V_{CC} = 15 V unless otherwise specified)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V _{io}	Input offset voltage	$V_{ic} = 0 \text{ V}, V_{o} = 7.5 \text{ V}$			6	mV
I _{io}	Input offset current	V 0VV 75V		4	40	nA
I _{ib}	Input bias current (1)	$V_{ic} = 0 \text{ V}, V_o = 7.5 \text{ V}$		100	200	nA
V _{icm}	Input common mode voltage range		0			V
V _{OL}	Low level output voltage	$R_L = 10 \text{ k}\Omega \text{ to } V_{CC}$		75	150	mV
V _{OH}	High level output voltage	$R_L = 10 \text{ k}\Omega \text{ to GND}$	14	14.7		V
	Output short circuit current	Source, V _{id} = +1; V _o = 0 V	16	30		mA
l _o	Output Short circuit current	Sink, V _{id} = -1; V _o = V _{CC}	50	80		mA
SR	Slew rate	$V_i = 1 \div 4 \text{ V; } C_L = 100 \text{ pF;}$ unity gain	2.5	3.8		V/μs
GBWP	Gain bandwidth product	V _o = 7.5 V	8	12		MHz
A _{vd}	Large signal voltage gain	$R_L = 2 k\Omega$	70	85		dB
SVR	Supply voltage rejection ratio	vs. V _{CC}	60	75		dB
CMRR	Common mode rejection ratio		55	70		dB

^{1.} The direction of input current is out of the IC.

Table 12. Sense comparator characteristics ($V_{CC} = 15 \text{ V}$ unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{ib(i)}	Input bias current	V _{CIN(i)} =1 V, i= U, V o W	-		3	μΑ
V _{ol}	Open-drain low-level output voltage	I _{od} = 3 mA	-		0.5	٧
t _{d_comp}	Comparator delay	SD/OD pulled to 5 V through 100 kΩ resistor	-	90	130	ns
SR	Slew rate	$C_L = 180 \text{ pF}; R_{pu} = 5 \text{ k}\Omega$	-	60		V/μsec
t _{sd}	Shut down to high / low side driver propagation delay	$V_{OUT} = 0$, $V_{boot} = V_{CC}$, $V_{IN} = 0$ to 3.3 V	50	125	200	
t _{isd}	Comparator triggering to high / low side driver turn-off propagation delay	Measured applying a voltage step from 0 V to 3.3 V to pin CIN _i	50	200	250	ns

Table 13. Truth table

Condition	Logic input (V _I)			Output		
Condition	SD	LIN	HIN	LVG	HVG	
Shutdown enable half-bridge tri-state	L	Х	х	L	L	
Interlocking half-bridge tri-state	Н	Н	Н	L	L	
0 ''logic state" half-bridge tri-state	Н	L	L	L	L	
1 "logic state" low side direct driving	Н	Н	L	Н	L	
1 "logic state" high side direct driving	Н	L	Н	L	Н	

Note: X: don't care

3.1.1 NTC thermistor

Table 14. NTC thermistor

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit.
R ₂₅	Resistance	T = 25°C		5		kΩ
R ₁₂₅	Resistance	T = 125°C		300		Ω
В	B-constant	T = 25°C to 85°C		3340		K
Т	Operating temperature		-40		125	°C

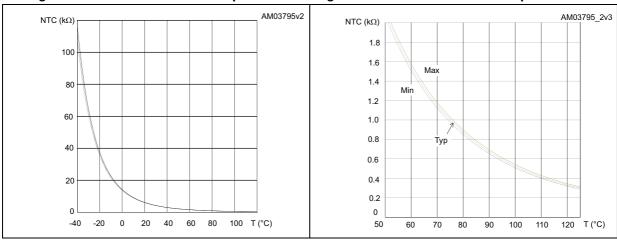
Equation 1: resistance variation vs. temperature

$$R(T) = R_{25} \cdot e^{B\left(\frac{1}{T} - \frac{1}{298}\right)}$$

Where T are temperatures in Kelvin.

Figure 5. NTC resistance vs. temperature

Figure 6. NTC resistance vs. temperature zoom



3.2 Waveforms definitions

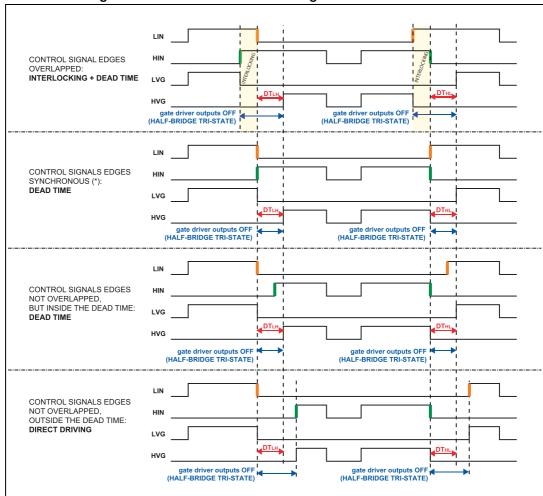
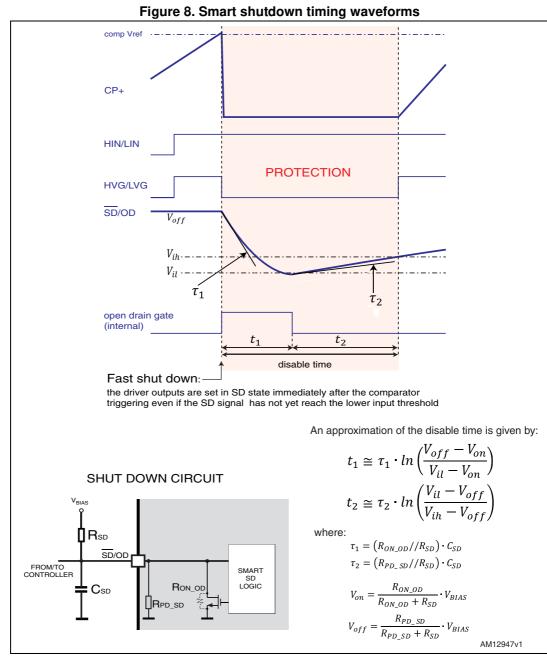


Figure 7. Dead time and interlocking waveforms definitions

4 Smart shutdown function

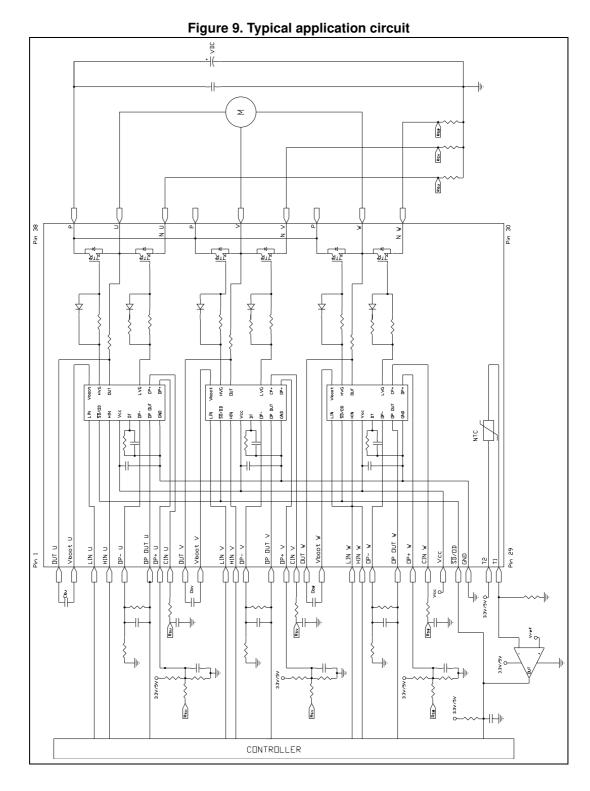
The STGIPL30C60-H integrates a comparator for fault sensing purposes. The comparator has an internal voltage reference V_{RFF} connected to the inverting input, while the noninverting input, available on pin (CIN), can be connected to an external shunt resistor in order to implement a simple over-current protection function. When the comparator triggers, the device is set in shutdown state and both its outputs are set to low-level leading the halfbridge in tri-state. In the common overcurrent protection architectures the comparator output is usually connected to the shutdown input through a RC network, in order to provide a mono-stable circuit, which implements a protection time that follows the fault condition. Our smart shutdown architecture allows to immediately turn-off the output gate driver in case of overcurrent, the fault signal has a preferential path which directly switches off the outputs. The time delay between the fault and the outputs turn-off is no more dependent on the RC values of the external network connected to the shutdown pin. At the same time the DMOS connected to the open-drain output (pin SD/OD) is turned on by the internal logic which holds it on until the shutdown voltage is lower than the logic input lower threshold (V_i). Finally, the smart shutdown function provides the possibility to increase the real disable time without increasing the constant time of the external RC network.

Smart shutdown function STGIPL30C60-H



Please refer to *Table 12* for internal propagation delay time details.

5 Applications information



5.1 Recommendations

- Input signals HIN, LIN are active high logic. A 375 k Ω (typ.) pull down resistor is built-in for each input. If an external RC filter is used, for noise immunity, pay attention to the variation of the input signal level.
- To prevent the input signals oscillation, the wiring of each input should be as short as possible.
- By integrating an application specific type HVIC inside the module, direct coupling to MCU terminals without any opto-coupler is possible.
- Each capacitor should be located as nearby the pins of IPM as possible.
- Low inductance shunt resistors should be used for phase leg current sensing.
- Electrolytic bus capacitors should be mounted as close to the module bus terminals as possible. Additional high frequency ceramic capacitor mounted close to the module pins will further improve performance.
- The SD/OD signal should be pulled up to 5 V / 3.3 V with an external resistor (see Section 4: Smart shutdown function for detailed info).

Table 15. Recommended operating conditions

Symbol	Parameter	Conditions	Value			Unit
	Farameter	Conditions	Min.	Тур.	Max.	Oilit
V _{PN}	Supply Voltage	Applied between P-Nu, Nv, Nw		300	400	V
V _{CC}	Control supply voltage	Applied between V _{CC} -GND	13.5	15	18	V
V _{BS}	High side bias voltage	Applied between V_{BOOTI} -OUT _i for $i = U, V, W$	13		18	V
t _{dead}	Blanking time to prevent Arm-short	For each input signal	1.5			μs
f _{PWM}	PWM input signal	-40°C < T _c < 100°C -40°C < T _j < 125°C			20	kHz
T _C	Case operation temperature				100	°C

Note: For further details refer to AN3338.

STGIPL30C60-H Package information

6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

Please refer to dedicated technical note TN0107 for mounting instructions.

Table 16. SDIP-38L mechanical data

Dimandana		mm.	
Dimensions -	Min.	Тур.	Max.
А	49.10	49.60	50.10
A1	1.10	1.30	1.50
A2	1.40	1.60	1.80
A3	44.10	44.60	45.10
В	24.00	24.50	25.00
B1	11.25	11.85	12.45
B2	27.10	27.60	28.10
B3	28.60	29.10	29.60
С	5.00	5.40	6.00
C1	6.50	7.00	7.50
C2	10.35	10.85	11.35
е	1.10	1.30	1.50
e1	3.20	3.40	3.60
e2	5.80	6.00	6.20
e3	4.60	4.80	5.00
e4	5.60	5.80	6.00
e5	6.30	6.50	6.70
e6	4.50	4.70	4.90
D		38.10	
D1		5.75	
Е		11.80	
E1		2.15	
F	0.85	1.00	1.15
F1	0.35	0.50	0.65
R	1.55	1.75	1.95
Т	0.45	0.55	0.65
V	0°		6°

Package information STGIPL30C60-H

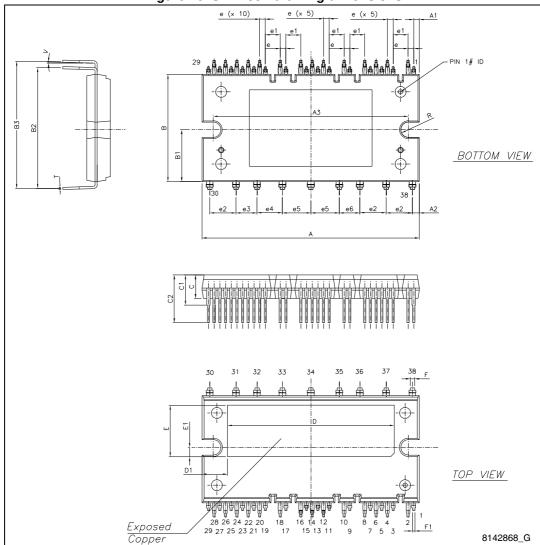


Figure 10. SDIP-38L drawing dimensions

STGIPL30C60-H Package information

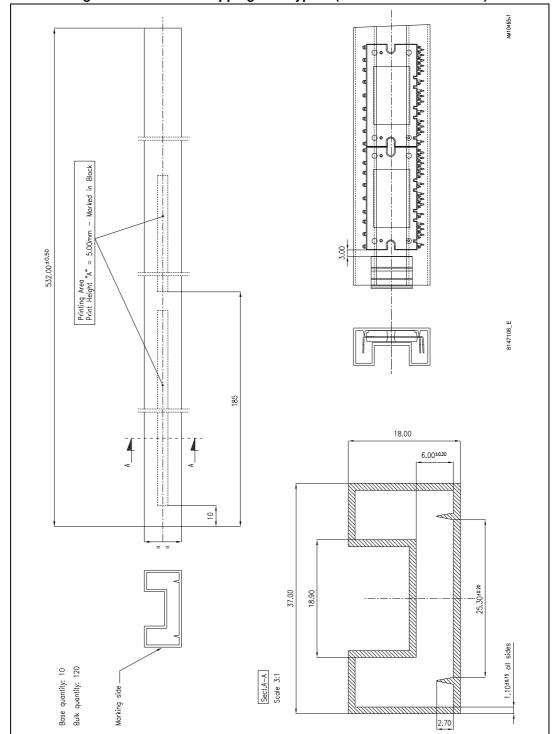


Figure 11. SDIP-38L shipping tube type A (dimensions are in mm.)

Package information STGIPL30C60-H

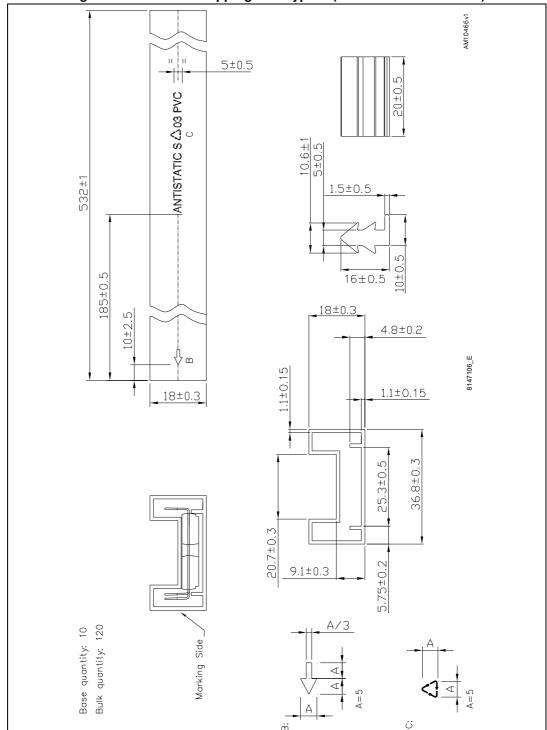


Figure 12. SDIP-38L shipping tube type B (dimensions are in mm.)

STGIPL30C60-H Revision history

7 Revision history

Table 17. Document revision history

Date	Revision	Changes
22-Apr-2013	1	Initial release
09-Jul-2013	2	Updated Dt value in <i>Table 10: Logic inputs (VCC = 15 V unless otherwise specified)</i> , t _{dead} in <i>Table 15: Recommended operating conditions</i> and V _F in <i>Table 7: Inverter part</i> .
12-Jul-2013	3	Document status promoted from target to preliminary data.
17-Jul-2013	4	Updated features in cover page.

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